

Ultra Low Outgassing™ SCV-2586

Silicone

NuSil Technology

Message:

Controlled Volatility (CV) Silicone Materials

Silicone's ability to remain elastic at low temperatures and resistant to breakdown at high temperatures offer excellent utility in extraterrestrial environments where materials are repeatedly exposed to extreme temperatures. NuSil's Controlled Volatility (CV) and Ultra Low Outgassing TM (SCV) silicone products are used by leading space programs to provide the much-needed resilient protection they require against contamination and material degradation.

Benefits of Silicone Materials for Space

Broad Operating Temperature

Compensation for CTE Mismatch

Protection Against Atomic Oxygen

Optically Clear Formulations

Flight Legacy

Comments: Fast Cure, Low Density, Primed Lap Shear 175psi

General Information		
Features	Fast Cure	
	Low Density	
	Low to No Outgassing	
Uses	Aerospace Applications	
Agency Ratings	ASTM E 595	
	NASA SP-R-0022A	
Thermoset	Nominal Value	Unit
Thermoset Components		
Part A	Mix Ratio by Weight: 1.0	
Part B	Mix Ratio by Weight: 1.0	
Additional Information	Nominal Value	Unit
Cure System	Platinum	
Uncured Properties	Nominal Value	Unit
Color	Red	
Density	0.738	g/cm ³
Viscosity		
-- 1	280	Pa · s
-- 2	380	Pa · s
Curing Time (150°C)	0.50	hr
Pot Life	240	min
Cured Properties	Nominal Value	Unit
Shore Hardness (Shore A)	45	
Lap Shear Strength	1.21	MPa
Tensile Strength	1.55	MPa

Tensile Elongation at Break	150	%
NOTE		
1.	Part B	
2.	Part A	

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Susheng Import & Export Trading Co.,Ltd.

Tel: +86 21 5895 8519

Phone: +86 13424755533

Email: sales@su-jiao.com

No. 215, Lianhe North Road, Fengxian District, Shanghai, China

